

FEATURES

- Large active area
- Photoconductive
- Low cost
- Lead frame

DESCRIPTION

The **PDB-C168** is a PIN silicon photodiode in a photoconductive mode packaged in a water clear plastic side looker package.

APPLICATIONS

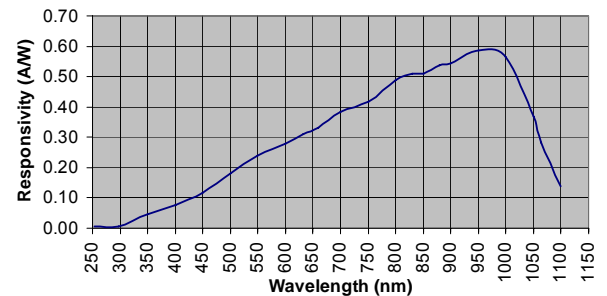
- Oximeters
- Dimmers
- TV & VCR remotes
- Bar code detectors

ABSOLUTE MAXIMUM RATING (TA)= 23°C UNLESS OTHERWISE NOTED

| SYMBOL | PARAMETER | MIN | MAX | UNITS |
|------------------|------------------------|-----|------|-------|
| V _{BR} | Reverse Voltage | | 100 | V |
| T _{STG} | Storage Temperature | -40 | +100 | °C |
| T _O | Operating Temperature | -40 | +80 | °C |
| T _S | Soldering Temperature* | | +260 | °C |

* 1/16 inch from case for 3 seconds max.

SPECTRAL RESPONSE



ELECTRO-OPTICAL CHARACTERISTICS RATING (TA)= 23°C UNLESS OTHERWISE NOTED

| SYMBOL | CHARACTERISTIC | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|-----------------|----------------------------|----------------------------------|-----|-----------------------|------|-------|
| I _{SC} | Short Circuit Current | H = 100 fc, 2850 K | 30 | 38 | | μA |
| I _D | Dark Current | V _R = 10 V | | 0.5 | 1 | nA |
| R _{SH} | Shunt Resistance | V _R = 10 mV | 100 | 200 | | MΩ |
| C _J | Junction Capacitance | V _R = 10 V, f = 1 MHz | | 60 | | pF |
| λ range | Spectral Application Range | Spot Scan | 350 | | 1100 | nm |
| V _{BR} | Breakdown Voltage | I = 10 μA | 33 | 80 | | V |
| NEP | Noise Equivalent Power | V _R = 10V @ λ = Peak | | 1.5x10 ⁻¹⁴ | | W/√Hz |
| t _r | Response Time | RL = 1KΩ, V _R = 10 V | | 100 | | nS |

**Response time of 10% to 90% is specified at 660nm wavelength light.

Information in this technical datasheet is believed to be correct and reliable. However, no responsibility is assumed for possible inaccuracies or omission. Specifications are subject to change without notice.